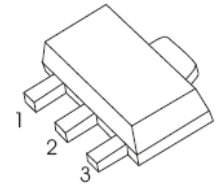


**SOT-89-3L Plastic-Encapsulate MOSFETS****CJA03N10S** N-Channel MOSFET

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
100V	140mΩ@ 10V	3A
	190mΩ@4.5V	

SOT-89-3L

1. GATE
2. DRAIN
3. SOURCE

DESCRIPTION

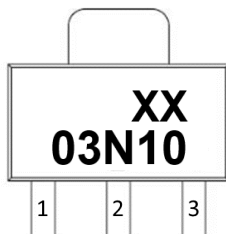
The CJA03N10S uses advanced trench technology and design to provide excellent $R_{DS(on)}$ with low gate charge. This device is suitable for use in a wide variety of applications.

FEATURES

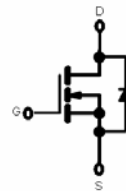
- Lead free product is acquired
- Special process technology for high ESD capability
- High density cell design for ultra low $R_{DS(on)}$
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

APPLICATION

- Power switching application
- Hard switching and high frequency circuits
- Uninterruptible power supply

MARKING

XX: Data Code

Equivalent Circuit**Maximum ratings ($T_a=25^\circ\text{C}$ unless otherwise noted)**

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	3	A
Pulsed Drain Current (note 1)	I_{DM}	20	A
Single Pulsed Avalanche Energy(note 5)	E_{AS}	25	mJ
Power Dissipation	P_D	0.5	W
Thermal Resistance from Junction to Ambient (note 2)	$R_{\theta JA}$	250	$^\circ\text{C/W}$
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55~+150	$^\circ\text{C}$

MOSFET ELECTRICAL CHARACTERISTICS

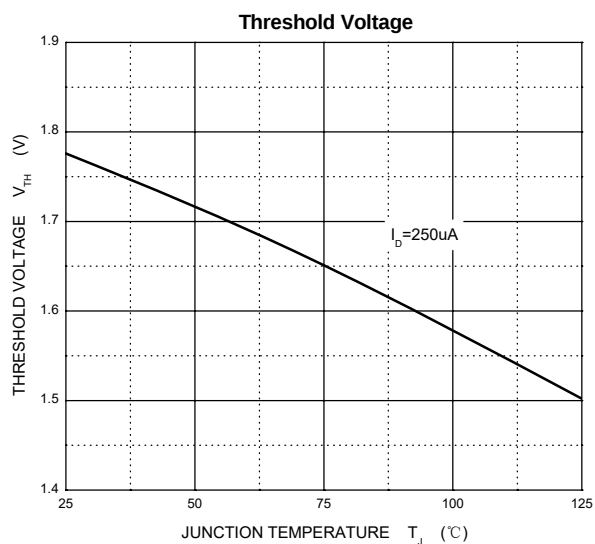
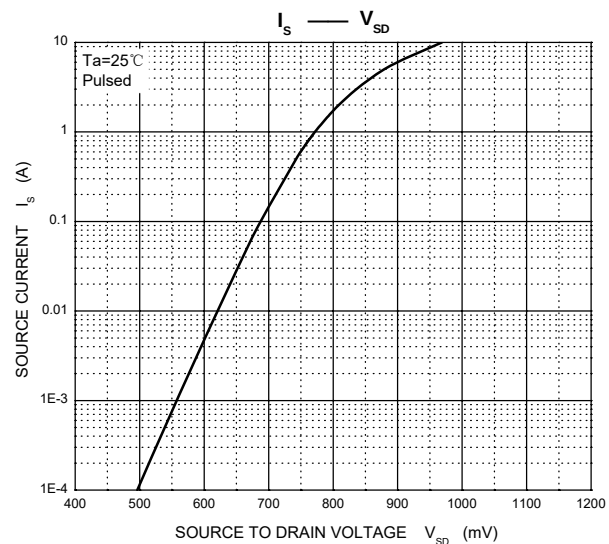
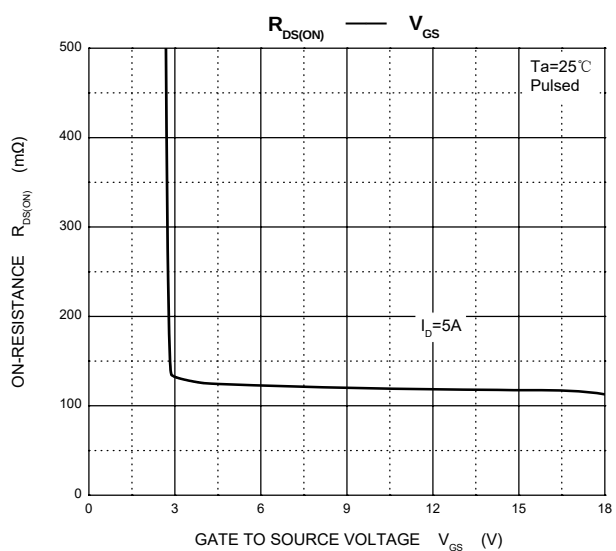
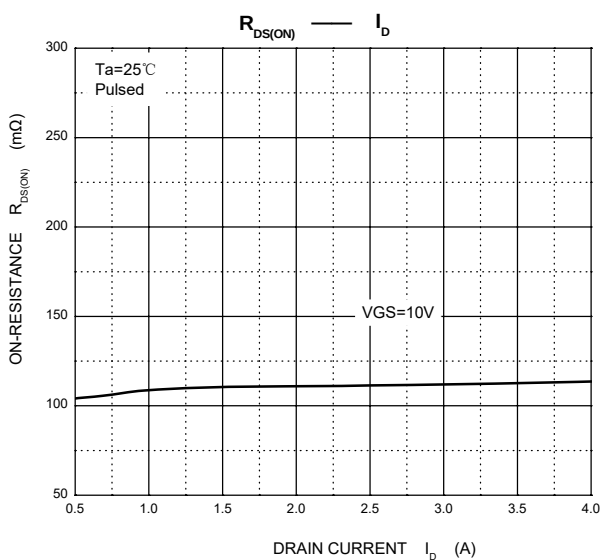
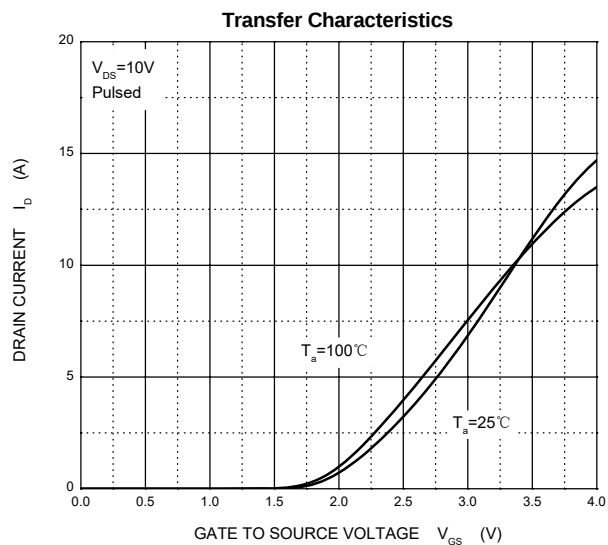
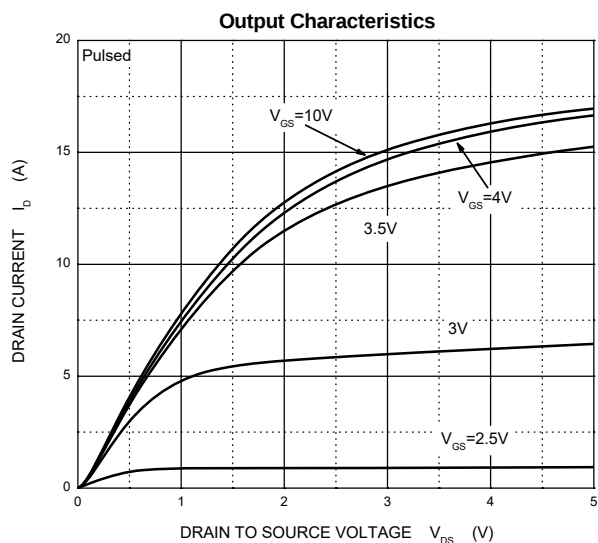
$T_a=25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
STATIC CHARACTERISTICS						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =250μA	100			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =100V,V _{GS} = 0V			1	μA
Gate-body leakage current	I _{GSS}	V _{GS} =±20V, V _{DS} = 0V			± 100	nA
Gate threshold voltage (note 3)	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	1	1.6	3	V
Drain-source on-resistance (note 3)	R _{DS(on)}	V _{GS} =10V, I _D =3A		113	140	mΩ
		V _{GS} =4.5V, I _D =2A		125	190	mΩ
Forward transconductance (note 3)	g _{FS}	V _{DS} =5V, I _D =2.9A	3			S
Diode forward voltage (note 3)	V _{SD}	I _S =3A, V _{GS} = 0V			1.2	V
DYNAMIC CHARACTERISTICS (note 4)						
Input capacitance	C _{iss}	V _{DS} =25V,V _{GS} =0V,f =1MHz		607		pF
Output capacitance	C _{oss}			38		pF
Reverse transfer capacitance	C _{rss}			20		pF
SWITCHING CHARACTERISTICS (note 4)						
Turn-on delay time	t _{d(on)}	V _{GS} =10V,V _{DS} =30V, R _{GEN} =2.5Ω, I _D =2A, R _L =15Ω		9.7		ns
Turn-on rise time	t _r			6.5		ns
Turn-off delay time	t _{d(off)}			31		ns
Turn-off fall time	t _f			8		ns
Total gate charge	Q _g	V _{DS} =30V,V _{GS} =10V,I _D =3A		13.7		nC
Gate-source Charge	Q _{gs}			3.1		nC
Gate-drain Charge	Q _{gd}			4.5		nC

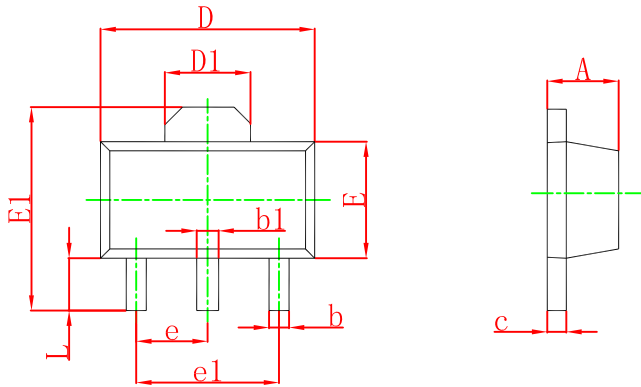
Notes :

1. Repetitive rating : Pulse width limited by junction temperature.
2. Surface mounted on FR4 board , $t_s \leq 10s$.
3. Pulse Test : Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
4. Guaranteed by design, not subject to producing.
5. EAS condition: $V_{DD} = 50V, V_{GS} = 10V, V_{GR} = 2V, L = 0.5mH, R_g = 25\Omega$ Starting $T_J = 25^\circ C$.

Typical Characteristics

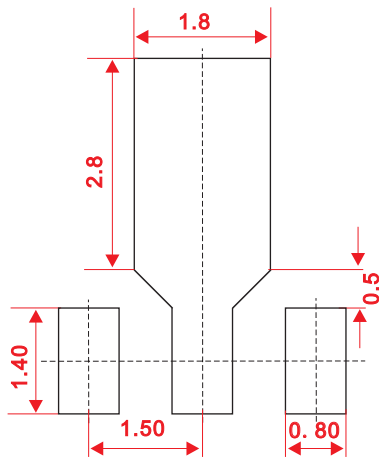


SOT-89-3L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550 REF.		0.061 REF.	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500 TYP.		0.060 TYP.	
e1	3.000 TYP.		0.118 TYP.	
L	0.900	1.200	0.035	0.047

SOT-89-3L Suggested Pad Layout



Note:

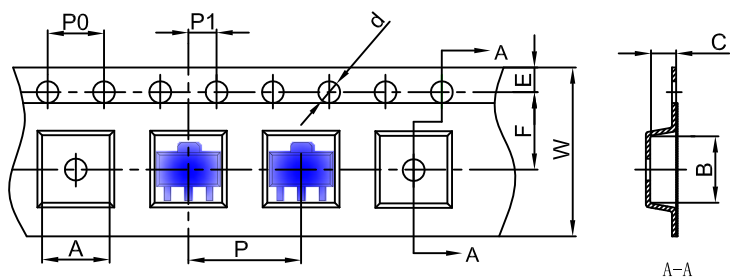
1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

NOTICE

JSCJ reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

SOT-89-3L Tape and Reel

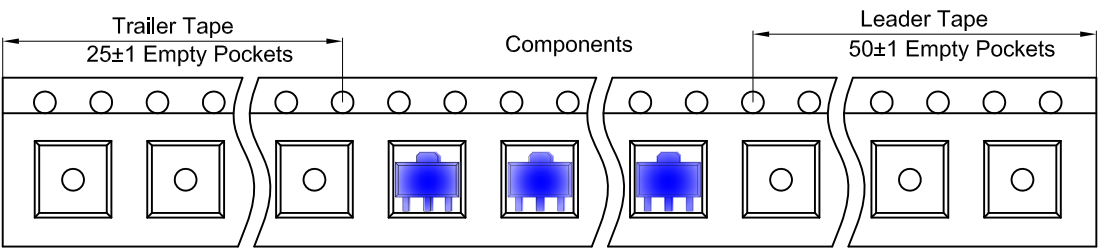
SOT-89-3L Embossed Carrier Tape



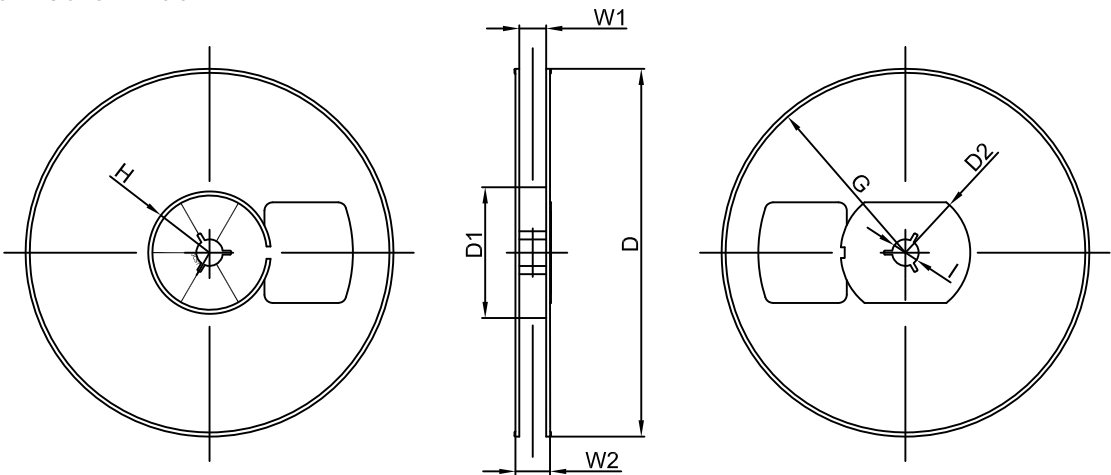
Packaging Description:
SOT-89-3L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 1,000 units per 7" or 18.0 cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-89-3L	4.85	4.45	1.85	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00

SOT-89-3L Tape Leader and Trailer



SOT-89-3L Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7"Dia	Ø180.00	60.00	R32.00	R86.50	R30.00	Ø13.00	13.20	16.50

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
1000 pcs	7 inch	10,000 pcs	203×203×195	40,000 pcs	438×438×220	